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LC Resonant Circuits Based Matching Networks for Continuous Mode MMIC Power Amplifiers

Yang Xu and Anding Zhu

Abstract—This paper presents a practical design methodology to construct output matching networks for broadband continuous mode monolithic microwave integrated circuit (MMIC) power amplifiers (PAs). Unlike conventional harmonic manipulation approaches, combinations of parallel and series LC resonant circuits are utilized to build the matching networks as it can generate frequency-dependent components and locate the varying impedance of continuous mode. With a proper design, the impedance variation in frequency domain can be mapped to the frequency response of the matching network at the fundamental frequency and the second harmonic simultaneously. Matching network design procedures are demonstrated and results show that the frequency response of the network has very good approximation with the desired continuous mode conditions. A prototype PA is implemented on 0.25-µm Gallium Nitride (GaN) MMIC process, and tested with both continuous-wave and modulated signals. Measurement results show 50.82% maximum drain efficiency and 8.5 dB gain can be achieved across the operation bandwidth of 5.4 to 6.4 GHz.

Keywords—Broadband, continuous mode, GaN, monolithic microwave integrated circuit (MMIC), power amplifiers

I. INTRODUCTION

With increasing demands for higher data rate and wider signal bandwidth, the broadband power amplifier (PA) with high efficiency is essential in the next generation, i.e., 5G, wireless systems. However, maintaining high efficiency over a wide bandwidth is difficult since bandwidth enhancement is often accompanied with efficiency degradation. The continuous mode PA has shown great potential in broadband PA design [1]. It introduces reactive load to the fundamental and harmonics matching, allowing PA to produce constant output power and maintain the same efficiency over a wide impedance range [2].

Despite many broadband continuous mode PAs have been reported [3][4][5][6], the output matching network design for broadband continuous mode operation is challenging as specific impedance requirements are enforced to guarantee the performance. The existing designs mainly rely on load-pull measurement and mostly are implemented with microstrip lines or filter-based matching networks [7][8][9]. Those discrete circuit design approaches deal with the characteristic impedance transmission lines, and have limited integration potential.

When 5G is evolving towards small cells, Monolithic Microwave Integrated Circuit (MMIC) with compact size is preferred for low power transmitters in dense networks. The MMIC process enables compact circuit design with high power density and reasonable efficiency [10][11][12]. The active devices can be adjusted for purpose, as observed in MMIC Doherty PA designs and multi-stage PA designs [13][14]. Moreover, in the designs involving harmonic manipulation, it is normally fulfilled with additional harmonic termination lines [15][16]. While the commonly used strategies for PCB is no longer effective for MMIC, we need to explore the lumped element based design approach outside the discrete circuits.

LC resonant circuits can provide precise impedance matching but it always involves complex mathematical circuit synthesis and the bandwidth is limited [17][18]. In this paper, a simple design approach utilizing LC resonant circuits is proposed to construct broadband continuous mode output matching networks. Different from most matching strategies using lumped components [19], it adopts LC resonant circuits not only to locate the harmonic reactance, but more importantly, to generate equivalent frequency-dependent components with different behaviors at the fundamental frequency and second harmonic. Thus, the continuous mode impedance requirements are satisfied in broadband without complicated network synthesis. The lumped component based design procedure is suitable for realistic MMIC implementation.

II. BROADBAND CONTINUOUS MODE MATCHING NETWORK CONSTRUCTION

In the continuous Class-B mode, the fundamental impedance \( Z_{f0} \) and second harmonic impedance \( Z_{2f0} \) can be expressed as [2]:

\[
Z_{f0} = R_{opt} - j\delta R_{opt} \tag{1}
\]

\[
Z_{2f0} = 0 + j\frac{3\pi}{8}\delta R_{opt} \tag{2}
\]

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where $R_{opt}$ is the optimum load and $\delta$ varies in a range of [-1,1]. The continuous mode impedance expands from a single point to a set of solutions, making the bandwidth extension possible. The operation principle is simple but realizing the continuous mode across a wide bandwidth is not easy. It can only be achieved when $\delta$ variations are properly mapped to the frequency response variations of the matching network. Specifically, when $\delta$ becomes a function of the frequency, the fundamental impedance trajectory variation must follow the opposite direction of that of the second harmonic, as shown in Fig. 1(a). Consequently, for the output matching network, the varying impedances at both frequencies must be converted to the load generated by frequency-dependent components. For instance, when $\delta$ stays inside [-1,0], the fundamental load has a positive reactance that equivalent to a frequency-dependent inductor $L_{eq}(f)$, and the negative second harmonic reactance can be viewed as a frequency-dependent capacitor $C_{eq}(2f)$, as shown in Fig. 1(b). Furthermore, the matching network is expected to keep constant fundamental resistance and let the second harmonic resistance stay zero inside the bandwidth. Building such matching networks is challenging.

As we know, a series $LC$ circuit acts as a short circuit when resonating, whereas a parallel $LC$ circuit acts as an open circuit when resonating. It would behave like a frequency-dependent component when deviating from its resonance frequency. For instance, when the operating frequency is lower than its resonance frequency $f_r$, the parallel $LC$ is equivalent to an inductor and when the operating frequency is higher than $f_r$, it is equivalent to a capacitor. Take a parallel $LC$ resonant circuit for example, when its operation frequency $f_0$ deviates from its resonance frequency $f_r$, its equivalent value can be expressed as

$$L_{parallel}(f) = L(1 - \frac{f_r}{f_0})^{-1}, \quad f_r > f_0$$

$$C_{parallel}(f) = C\left(1 - \frac{f_r^2}{f_0^2}\right), \quad f_r < f_0$$

This property is useful when constructing output matching networks for broadband continuous mode. Not only can it generate short or open circuit, but also it can create the frequency-dependent component which can be utilized to model the behavior of $L_{eq}(f)$ and $C_{eq}(2f)$. When combining series and parallel $LC$ circuits together, it is possible to construct broadband matching networks that meet continuous mode impedance requirements without going through complex circuit synthesis.

Fig. 2(a) shows a possible combination with two $LC$ units, and one possible circuit structure is proposed in Fig. 2(b). Resonant Circuit 1, including drain bias inductor $L_b$ and output capacitance $C_{out}$, resonates between the fundamental frequency and the second harmonic. Resonant Circuit 2 whose resonance frequency $f_2$ equals to the second harmonic is placed in series. $C_2$ is added in between and it can serve as the DC block capacitor. $C_3$ is placed in parallel to attain better fundamental resistance fitting and larger reactance adjustment range at the second harmonic.

Once chosen the topology, the frequency response of the network can be determined through analyzing the equivalent circuits at both frequencies, shown in Fig. 2(c) and Fig. 2(d), respectively. At the second harmonic, the open circuit created by Resonant Circuit 2 locates the second harmonic load at the edge of the Smith Chart. Resonant Circuit 1 is equivalent to the frequency-dependent component $C_{eq}(f)$. The behavior of $C_{eq}(2f)$ is mainly decided by $C_{eq}(f)$, which can be expressed as the function of $f_{1r}$ based on its resonance characteristics. The second harmonic reactance and the corresponding $\delta(2f)$ are functions of $f_{1r}$, $C_2$ and $C_3$. At the fundamental frequency, $L_{1r}$ and $L_{2r}$ are the equivalent frequency-dependent inductors from two resonant circuits. Similarly, $L_{1r}$ is the function of $f_{1r}$, and $L_{2r}$ has $L_{2r}=4/3 L_1$ since it resonates at $2f_0$. All those variables jointly model the fundamental load and its corresponding $\delta(f)$. After the desired frequency response is determined, each component

![Fig. 1. Broadband continuous Class-B mode operation. (a) $\delta$ variation in the frequency domain. (b) The equivalent frequency-dependent components at the fundamental frequency and second harmonic for $\delta$ inside [-1,0].](image1)

![Fig. 2. The matching network construction procedure. (a) The general topology with two LC resonant circuits. (b) The proposed circuit structure based on (a). (c) The equivalent circuit at the fundamental frequency. (d) The equivalent circuit at the second harmonic.](image2)

### Table 1

<table>
<thead>
<tr>
<th>Variable</th>
<th>Value range</th>
<th>Optimal value</th>
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<tbody>
<tr>
<td>$f_0$ (GHz)</td>
<td>[6.50, 7.55]</td>
<td>7.66</td>
</tr>
<tr>
<td>$L_0$ (nH)</td>
<td>[2.01, 2.85]</td>
<td>2.06</td>
</tr>
<tr>
<td>$f_0$ (GHz)</td>
<td>[9.00, 13.00]</td>
<td>10.41</td>
</tr>
<tr>
<td>$L_1$ (nH)</td>
<td>[0.10, 1.09]</td>
<td>1.07</td>
</tr>
<tr>
<td>$C_1$ (pF)</td>
<td>[0.14, 3.00]</td>
<td>0.22</td>
</tr>
<tr>
<td>$C_2$ (pF)</td>
<td>[0.11, 3.00]</td>
<td>0.31</td>
</tr>
<tr>
<td>$C_3$ (pF)</td>
<td>[0.10, 0.58]</td>
<td>0.21</td>
</tr>
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![Image](image3)
value can be found by using optimization algorithms, e.g., the Bayesian Optimization (BO) in [20]. In this design, the selected transistor has $R_{opt} = 140 \, \Omega$ and $C_{out} = 0.21 \, pF$, and all component values are limited by the MMIC process. $\delta$ is expected to stay inside $[-1,0]$ at operating bandwidth from 4.5 GHz to 6.5 GHz. Objective functions are defined in BO to model the matching network with the target of searching for the optimal fitting. The optimal estimation given by BO are listed in Table 1.

Fig. 3 shows the simulated performance based on the optimal estimation. The fundamental resistance follows $R_{opt}$ very well, especially at lower frequency, whereas it starts to deviate at higher frequency but the discrepancy is still acceptable when it comes to practical applications. The second harmonic resistance locates at the edge of Smith Chart, meaning Resonate Circuit 2 has successfully removed the impact of the load. The predicted optimal $\delta$ range is estimated as $[-0.7, -0.2]$, where the behavior of $\delta(f)$ and $\delta(2f)$ fit well with the desired impedance trajectory inside the bandwidth. $\delta$ varies with increasing frequency in a linear fashion from -0.7 to -0.2 is also presented in the figure for reference.

III. CIRCUIT IMPLEMENTATION AND MEASUREMENTS

The circuit was implemented with 0.25-\mu m GaN HEMT from WIN Semiconductors, and the transistor with size $4 \times 125 \, \mu m$ was biased at $V_D = 28 \, V$ and $V_G = -2.5 \, V$. The output matching network was designed based on the optimal estimations, and the input matching network was designed based on source pull. The inductors in the proposed circuit structure were replaced with MMIC transmission lines.

The circuit schematic and chip photograph are shown in Fig. 4 (a). The chip size is 2 mm x 1 mm and the fabricated chip is mounted on a PCB test fixture with bonding wires for measurement. Continuous wave (CW) measurement results and simulation results are compared in Fig. 4 (b) and Fig. 4(c). Simulation results have taken the parasitic effect, the bonding wire impact and the thermal problem into consideration, and the PCB test fixture has been de-embedded. From the results, the efficiency degrades at the lower frequency band, leading to a reduction in bandwidth. The deviation of measurement results from simulation is mainly due to real circuits implementation and MMIC fabrication variations. Measured highest drain efficiency can reach 50.82% at 5.8 GHz and over 36.8% drain efficiency can be obtained from 5.4 GHz to 6.4 GHz. Measured gain can reach 10.19 dB at 6.2 GHz, and more than 8.5 dB gain is achieved from 5.4 GHz to 6.4 GHz.

The modulated signal measurements were performed inside the available measured bandwidth with a 20 MHz LTE signal
under 12 dBm input signal. Fig. 4(d) and Fig. 4(e) show the output spectrum for 5.4 GHz and 6.2 GHz carrier before and after digital predistortion (DPD). The adjacent channel power ratio (ACPR) is lower than -50 dBc after DPD at 5.4 GHz, ACPR at 6.2 GHz is slightly higher but remains -45 dBc.

The state-of-the-art comparison is shown in Table 2. The proposed PA has small size and is operated at relatively higher frequencies with comparable bandwidth. The efficiency performance may need to be further improved. Most publications using different architectures that are either involving higher harmonic control or adopting larger transistor size for better output matching and all of them involve complicated design process. In this paper, we demonstrated, for the first time, how to construct matching networks for continuous mode PAs by directly utilizing the special characteristics of LC resonance circuits without complex mathematical circuit synthesis. It provides a simple and alternative approach for PA designers in MMIC implementation.

IV. CONCLUSION

A new methodology for constructing broadband continuous mode PA output matching networks was presented. A GaN MMIC PA was fabricated, and the experimental results show maximum 50.82% drain efficiency and 10.19 dB gain were obtained. Various matching networks can be generated by using the proposed procedures, and those can be applied to any other frequencies in different designs.

REFERENCES